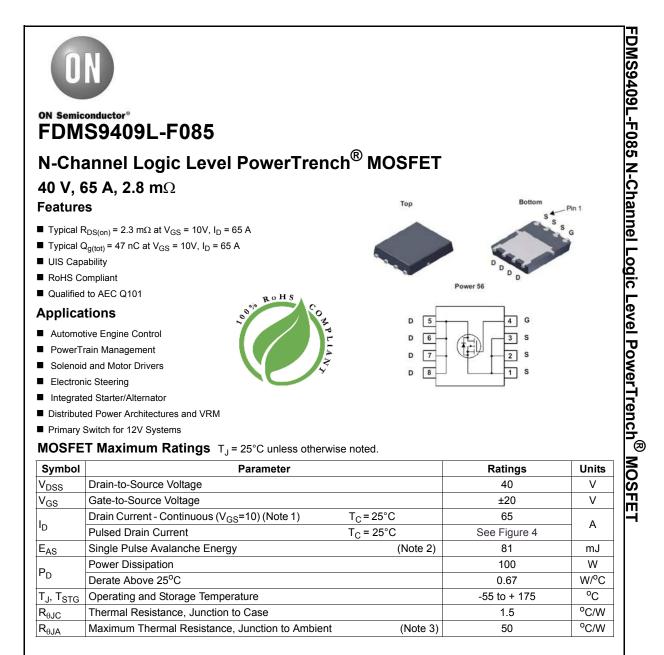
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Notes:

1: Current is limited by bondwire configuration.

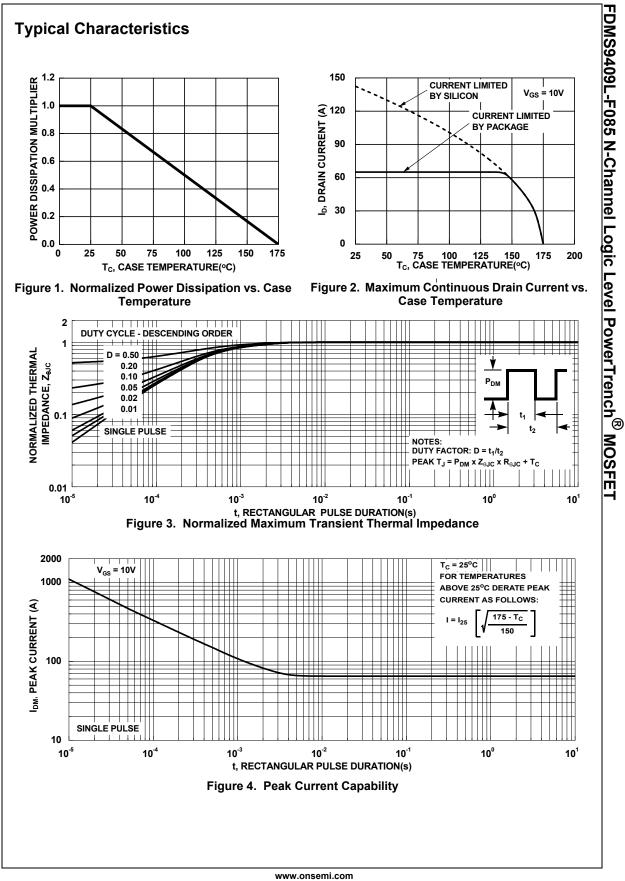
2: Starting $T_J = 25^{\circ}$ C, $L = 60\mu$ H, $I_{AS} = 52A$, $V_{DD} = 40V$ during inductor charging and $V_{DD} = 0V$ during time in avalanche.

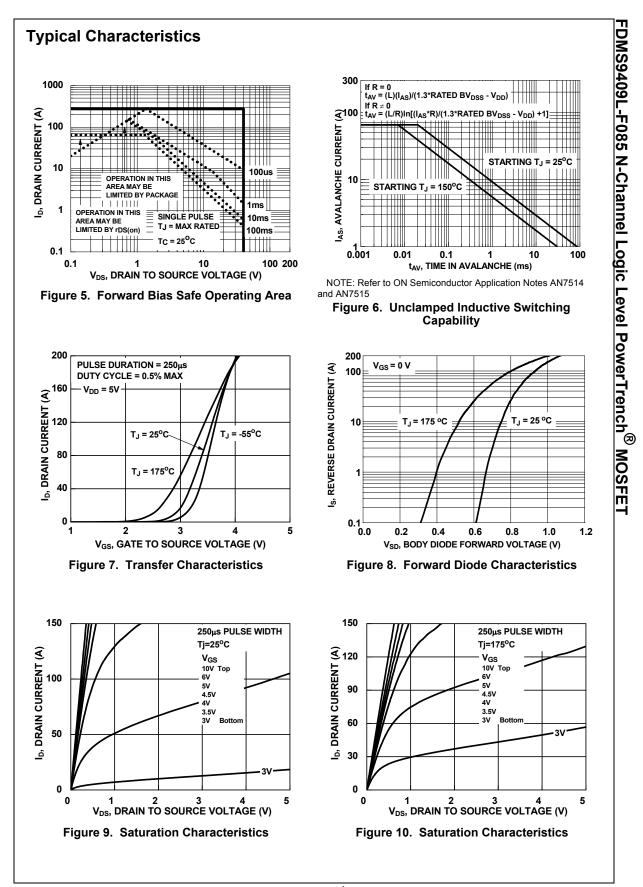
3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

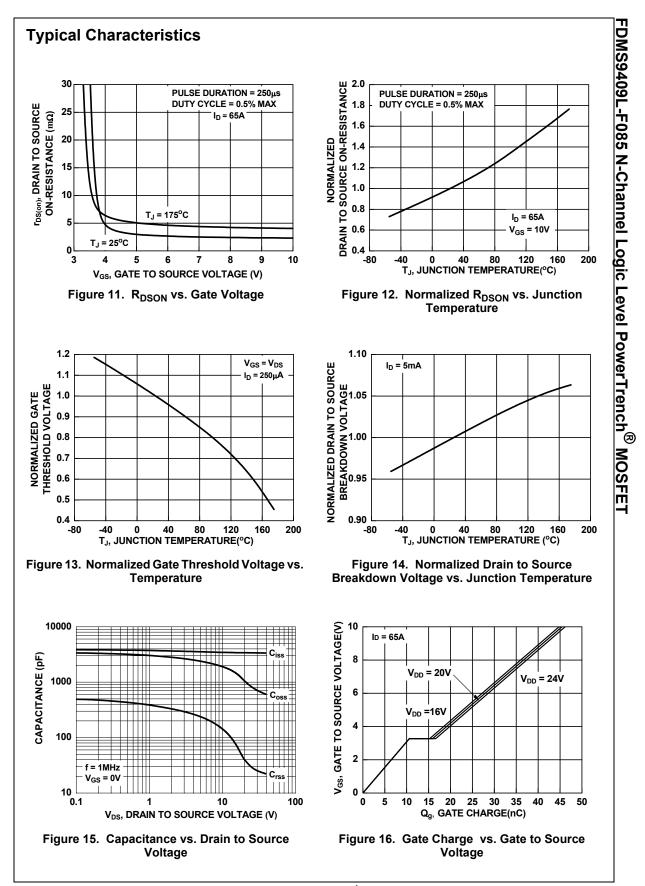
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS9409L	FDMS9409L-F085	Power56	13"	12mm	3000units

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		40	-	-	V
IDSS	Drain-to-Source Leakage Current	$V_{\rm DS}$ =40V, $T_{\rm J}$ = 25°C		-	-	1	μA
		$V_{GS} = 0V$	$T_{\rm J} = 175^{\rm o}C$ (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA		1.0	1.8	3.0	V
R _{DS(on)}	Drain to Source On Resistance	I _D = 65A, V _{GS} = 4.5V		-	3.3	4.5	mΩ
		I _D = 65A,		-	2.3	2.8	mΩ
		V _{GS} = 10V	T _J = 175 ^o C (Note 4)	-	4.0	5.0	mΩ
-	c Characteristics				0000		
C _{iss}	Input Capacitance	──V _{DS} = 20V, V _{GS} = 0V, f = 1MHz		-	3360	-	pF
C _{oss}	Output Capacitance			-	1080	-	pF
C _{rss}	Reverse Transfer Capacitance Gate Resistance	f - 1ML -		-	42 2.2	-	pF Ω
R _g	Total Gate Charge	f = 1MHz		-	47	- 70	nC
Q _{g(ToT)}	Threshold Gate Charge			-	6	-	nC
Q _{g(th)} Q _{gs}	Gate-to-Source Gate Charge			-	10	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge		-	-	6	-	nC
	ng Characteristics					<u> </u>	
t _{on}	Turn-On Time			-	-	28	ns
t _{d(on)}	Turn-On Delay		t	-	12	-	ns
t _r	Rise Time	V_{DD} = 20V, I_D = 65A, V_{GS} = 10V, R_{GEN} = 6 Ω		-	7	-	ns
t _{d(off)}	Turn-Off Delay			-	35	-	ns
t _f	Fall Time			-	8	-	ns
t _{off}	Turn-Off Time			-	-	64	ns
	ource Diode Characteristics				1	L	
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} =65A, V _{GS} = 0V		-	-	1.25	V
		I _{SD} = 32.5A		-	-	1.2	V
t _{rr}	Reverse-Recovery Time	I _F = 65A, dI _{SD} /dt = 100A/μs V _{DD} = 32V		-	59	77	ns
Q _{rr}	Reverse-Recovery Charge			-	58	75	nC





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